## Unit-4

## Lecture -4

Characteristics, Reponse Time

#### Characteristics of Photodetectors

• Internal Quantum Efficiency

$$\eta_i = \frac{\text{Number of Collected electrons}}{\text{Number of Photons *Entering* detector}} = \left[1 - e^{-\alpha W}\right]$$

•External Quantum efficiency

$$\eta_e = \frac{\text{Number of Collected electrons}}{\text{Number of Photons *Incident* on detector}} = \frac{\underline{i_{ph}}/\underline{q}}{P_o/h_V} = (1 - R_p) \left[1 - e^{-\alpha W}\right]_{\perp}$$

Responsivity

$$R = \frac{\text{Photo Current (Amps)}}{\text{Incident Optical Power (Watts)}} = \frac{\underline{i}_{ph}}{P_o} = \frac{q}{h_V} (1 - R_p) \left[ 1 - e^{-\alpha W} \right]$$

Photocurrent

Fraction Transmitted into Detector
$$i_{ph} = q \begin{bmatrix} P \\ \overline{hV} \end{bmatrix} (1 - R_p) \begin{bmatrix} 1 - e^{-\alpha W} \end{bmatrix} = RP_o$$

Incident Photon Flux (#/sec)

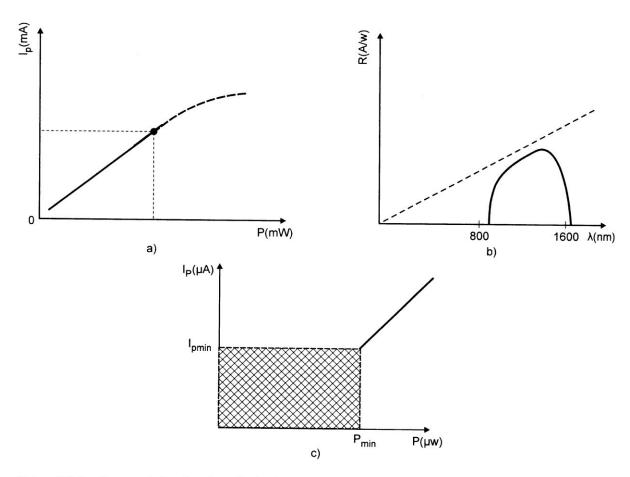
Incident Photon Flux Fraction absorbed in

# Responsivity

Output current per unit incident light power; typically 0.5 A/W

$$R = \frac{\eta e}{h \nu} M$$

# Photodiode Responsivity



**Figure 11.2** Responsivity of a photodiode: (a) Input–output characteristic; (b) responsivity vs. wavelength; (c) dark-current sensitivity.